

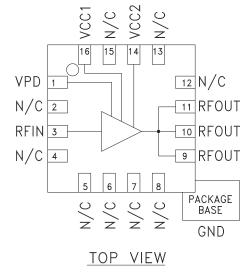


Typical Applications

The HMC408LP3 / HMC408LP3E is ideal for:

- 802.11a & HiperLAN WLAN
- UNII & Point-to-Point / Multi-Point Radios
- Access Point Radios

Functional Diagram



HMC408LP3 / 408LP3E

GaAs InGaP HBT MMIC 1 WATT POWER AMPLIFIER, 5.1 - 5.9 GHz

Features

Gain: 20 dB Saturated Power: +32.5 dBm @ 27% PAE Single Supply Voltage: +5V Power Down Capability 3x3 mm Leadless SMT Package

General Description

The HMC408LP3 & HMC408LP3E are 5.1 - 5.9 GHz high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) Power Amplifier MMICs which offer +30 dBm P1dB. The amplifier provides 20 dB of gain, +32.5 dBm of saturated power, and 27% PAE from a +5V supply voltage. The input is internally matched to 50 Ohms while the output requires a minimum of external components. Vpd can be used for full power down or RF output power/current control. The amplifier is packaged in a low cost, 3x3 mm leadless surface mount package with an exposed base for improved RF and thermal performance.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vs = 5V, Vpd = 5V

Parameter		Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range			5.7 - 5.9	-		5.1 - 5.9		GHz
Gain		17	20		17	20		dB
Gain Variation Over Temperature			0.045	0.055		0.045	0.055	dB/°C
Input Return Loss			8			8		dB
Output Return Loss*			14			6		dB
Output Power for 1 dB Compression (P1dB)	lcq= 750 mA lcq= 500 mA	27	30 27		24	27 23		dBm
Saturated Output Power (Psat)			32.5			31		dBm
Output Third Order Intercept (IP3)		40	43		36	39		dBm
Harmonics, Pout= 30 dBm, F= 5.8 GHz	2 fo 3 fo		-50 -90			-50 -90		dBc dBc
Noise Figure			6			6		dB
Supply Current (Icq)	Vpd= 0V/5V		0.002 / 750			0.002 / 750		mA
Control Current (Ipd)	Vpd= 5V		14			14		mA
Switching Speed	tOn, tOff		50			50		ns

* Output match optimized for 5.7 - 5.9 GHz operation. See Application Circuit herein.

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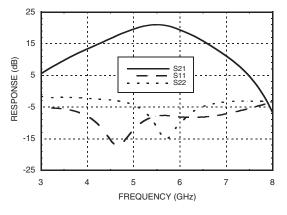
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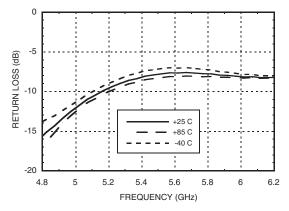




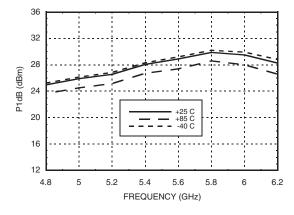
Broadband Gain & Return Loss



Input Return Loss vs. Temperature



P1dB vs. Temperature



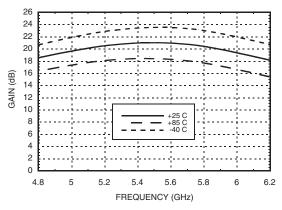
* Output match optimized for 5.7 - 5.9 GHz.

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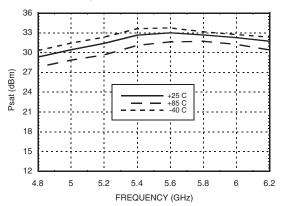
Gain vs. Temperature



Output Return Loss vs. Temperature*

FREQUENCY (GHz)

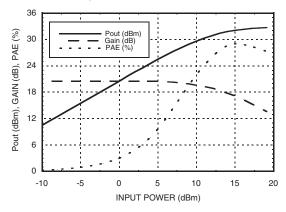
Psat vs. Temperature



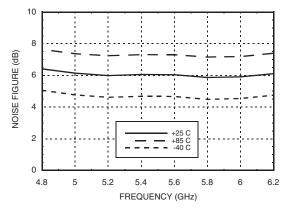




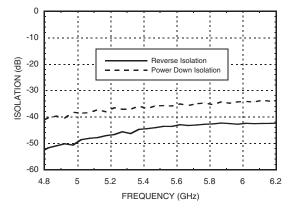
Power Compression @ 5.8 GHz



Noise Figure vs. Temperature



Reverse Isolation vs. Temperature



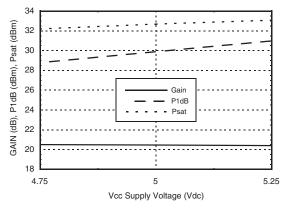
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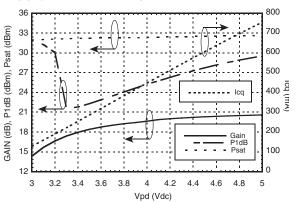
42 39 IP3 (dBm) 36 +25 C +85 C -40 C 33 . 30 5 5.2 6 6.2 4.8 5.6 5.8 5.4 FREQUENCY (GHz)

Gain & Power vs. Supply Voltage @ 5.8 GHz

Output IP3 vs. Temperature



Gain, Power & Quiescent Supply Current vs. Vpd @ 5.8 GHz



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Absolute Maximum Ratings

Collector Bias Voltage (Vcc1, Vcc2)	+5.5 Vdc
Control Voltage (Vpd)	+5.5 Vdc
RF Input Power (RFIN)(Vs = Vpd = +5Vdc)	+20 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 72.5 mW/°C above 85 °C)	4.71 W
Thermal Resistance (junction to ground paddle)	13.8 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

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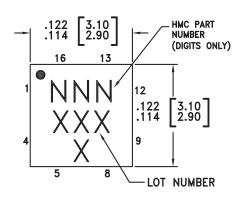
Typical Supply Current vs. Vs= Vcc1 + Vcc2

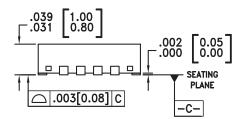
Vs (V)	lcq (mA)
4.75	725
5.0	750
5.25	780

Note: Amplifier will operate over full voltage range shown above



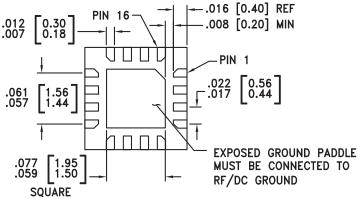
Outline Drawing





PIN 16

BOTTOM VIEW



NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM. 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB BE GROUND
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

-				
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC408LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	408 XXXX
HMC408LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>408</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vpd	Power control pin. For maximum power, this pin should be connected to 5V. A higher voltage is not recommended. For lower idle current, this voltage can be reduced.	OVPD
2, 4, 5 - 8, 12, 13, 15	N/C	No Connection	
3	RFIN	This pin AC coupled and matched to 50 Ohms.	
9, 10, 11	RFOUT	RF output and DC bias for the output stage.	
14	Vcc2	Power supply voltage for the second amplifier stage. Exter- nal bypass capacitors and pull up choke are required as shown in the application schematic.	OVCC1 VCC2
16	Vcc1	Power supply voltage for the first amplifier stage. External bypass capacitors are required as shown in the application schematic.	
	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.	GND =

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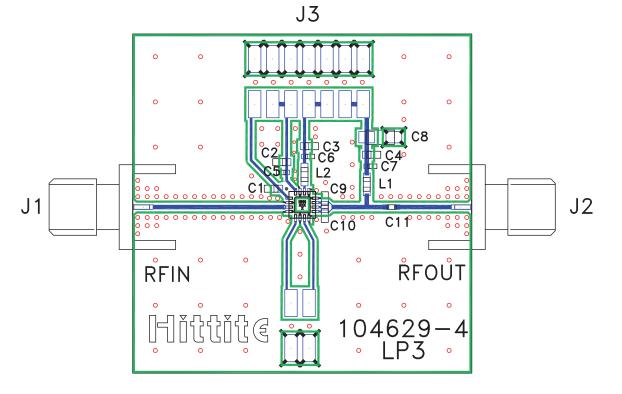


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GaAs InGaP HBT MMIC 1 WATT POWER AMPLIFIER, 5.1 - 5.9 GHz



Evaluation PCB



v03.0705

List of Materials for Evaluation PCB 105180 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	2 mm DC Header
C1 - C4	1,000 pF Capacitor, 0603 Pkg.
C5 - C7	100 pF Capacitor, 0402 Pkg.
C8	2.2 µF Tantalum Capacitor
C9 - C10	0.5 pF Capacitor, 0603 Pkg.
C11	10 pF Capacitor, 0402 Pkg.
L1 - L2	1.6 nH Inductor, 0603 Pkg.
U1	HMC408LP3 / HMC408LP3E Amplifier
PCB [2]	104629 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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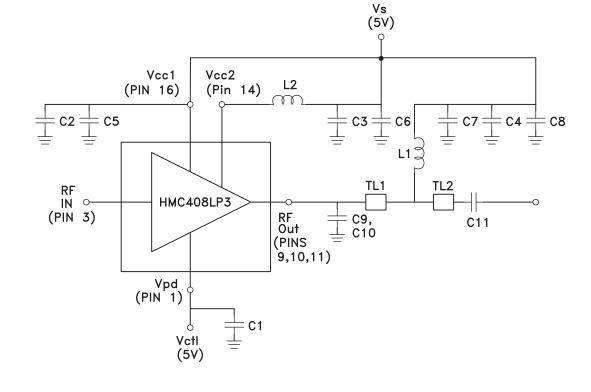
HMC408LP3 / 408LP3E

v03.0705





Application Circuit



Recommended C	Recommended Component Values		
L1, L2	1.6 nH		
C1 - C4	1,000 pF		
C5 - C7	100 pF		
C8	2.2 μF		
C9 - C10	0.5 pF		

	TL1	TL2
Impedance	50 Ohm	50 Ohm
Length	0.200"	0.100"

Note 1: C9, C10 should be located < 0.020" from pins 9, 10, & 11.

Note 2: Application circuit values shown are optimized for 5.7 - 5.9 GHz operation.

Contact our Applications Engineers for optimization of output match for other frequencies.

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